

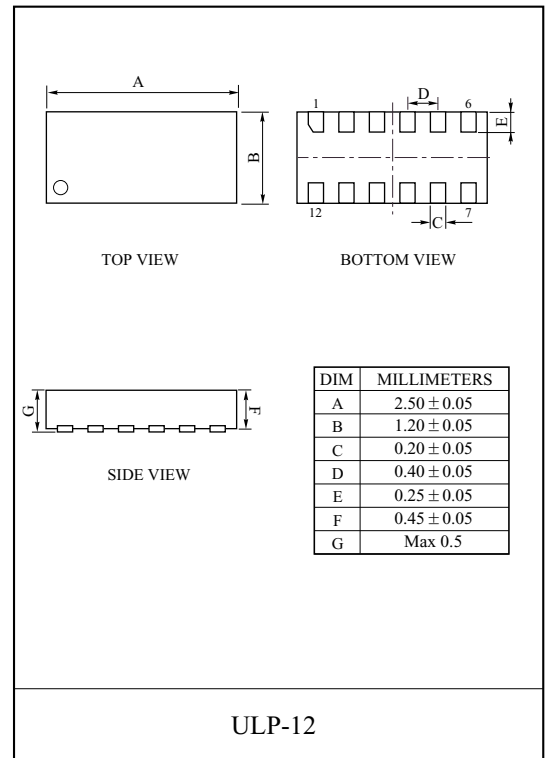
For antenna switches in mobile applications.

FEATURES

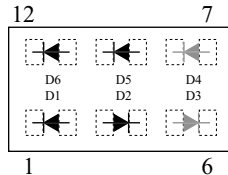
- Array type (6 Diode in one package)
- Low Capacitance
- Low Series resistance

MAXIMUM RATING (Ta=25 °C)

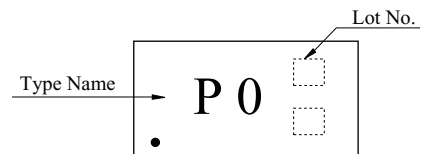
CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	V_R	30	V
Forward Current	I_F	100	mA
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	



EQUVALENT CIRCUIT (TOP VIEW)



Marking



D1, D2, D5, D6 ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Current	I_R	$V_R=30V$	-	-	0.1	μA
Forward Voltage	V_F	$I_F=10mA$	-	-	1.0	V
Total Capacitance	C_T	$V_R=1V, f=1MHz$	-	-	0.30	pF
Series Resistance	r_s	$I_F=10mA, f=100MHz$	-	-	1.3	
ESD-Capability *	-	$C=200pF, R=0 \Omega$, Both forward and reverse direction 1 pulse	100	-	-	V

* Failure criterion : $I_R > 100nA$ at $V_R=30V$.

KDP620UL

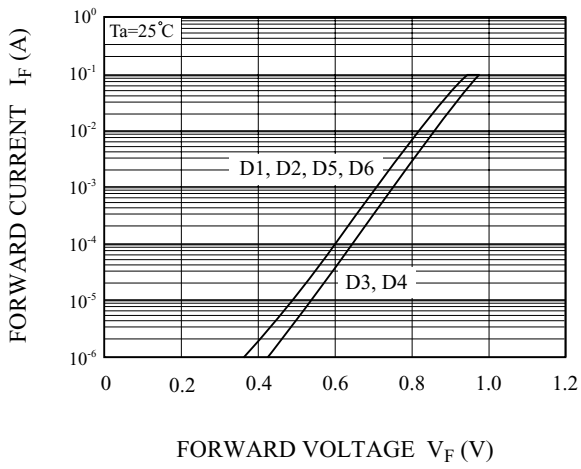
D3, D4 ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Current	I_R	$V_R=30V$	-	-	0.1	μA
Forward Voltage	V_F	$I_F=2mA$	-	-	0.9	V
Total Capacitance	C_T	$V_R=1V, f=1MHz$	-	-	0.43	pF
Series Resistance	r_s	$I_F=2mA, f=100MHz$	-	-	1.8	
ESD-Capability *	-	$C=200pF, R=0$, Both forward and reverse direction 1 pulse	100	-	-	V

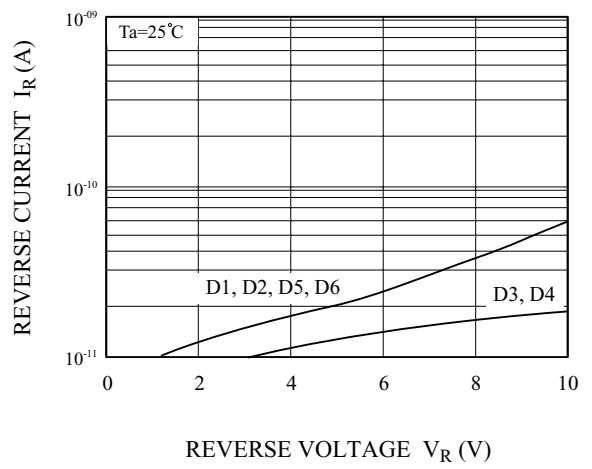
* Failure criterion : $I_R > 100nA$ at $V_R = 30V$.

KDP620UL

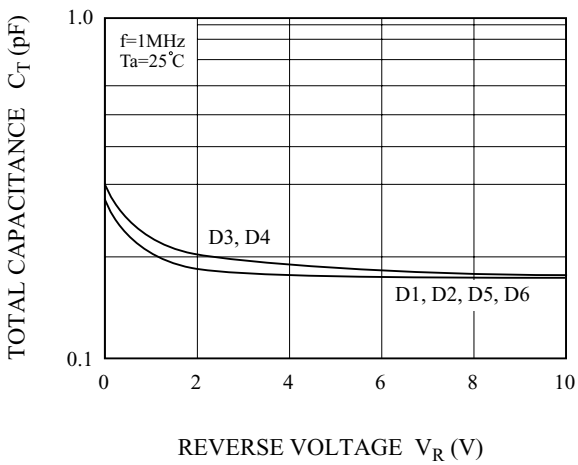
$I_F - V_F$



$I_R - V_R$



$C_T - V_R$



$r_s - I_F$

